NSN 5962-01-373-5207

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+175.0 degrees celsius
End Application:
Peacekeeper missile guidance control set, imu
Features Provided:
Burn in and radiation hardened and electrostatic sensitive and dielectric isolated and monolithic and 3-state output and programmable
Inclosure Configuration:
Flat pack
Criticality Code Justification:
Feat
Terminal Surface Treatment:
Solder
Product Name:
Integrated circuit, dielectrically isolated, 256 x 4 field programmable read-only memory (prom) with three-state outputs (electrostatic
sensitive)
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
6.00 nanoseconds propagation delay time, high to low level output and 90.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom
Special Features:
Electrostatic discharge sens/hardness critical item
Terminal Type And Quantity:
16 beam lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0